

Midium Power Transistors (-80V / -0.7A)

2SAR514R

Features

1) Low saturation voltage, typically $V_{CE (sat)} = -0.4 V (Max.) (I_C / I_B = -300 mA / -15 mA)$

2) High speed switching

Structure

PNP Silicon epitaxial planar transistor

Applications

Driver

Packaging specifications

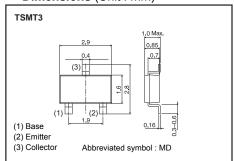
_	Package	TSMT3
	Code	TL
	Basic ordering unit (pieces)	3000

● Absolute maximum ratings (Ta = 25°C)

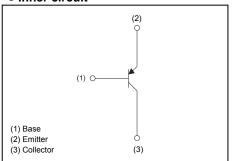
Parameter		Symbol	Limits	Unit	
Collector-base voltage		V_{CBO}	-80	V	
Collector-emitter voltage		V_{CEO}	-80	V	
Emitter-base voltage		V_{EBO}	-6	V	
Collector current	DC	Ic	-0.7	Α	
	Pulsed	I _{CP} *1	-1.4	Α	
Power dissipation		P _D *2	0.5	W	
		P _D *3	1.0	W	
Junction temperature		T _j	150	°C	
Range of storage temperature		T _{stg}	-55 to 150	°C	

^{*1} Pw=10ms, Single Pulse

Dimensions (Unit : mm)



• Inner circuit



^{*2} Mounted on a recommended land.

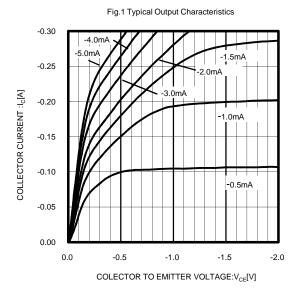
^{*3} Mounted on a 40 x 40 x 0.7[mm³] ceramic substrate.

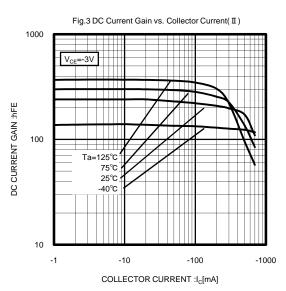
● Electrical characteristic (Ta = 25°C)

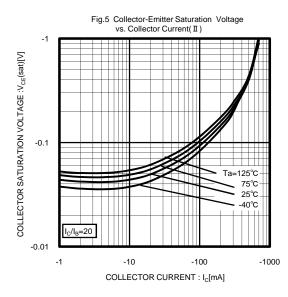
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-emitter breakdown voltage	BV_{CEO}	-80	-	-	V	I _C = -1mA	
Collector-base breakdown voltage	BV_{CBO}	-80	-	-	V	I _C = -100μA	
Emitter-base breakdown voltage	BV_{EBO}	-6	-	-	V	I _E = -100μA	
Collector cut-off current	I_{CBO}	-	-	-1	μA	V _{CB} = -80V	
Emitter cut-off current	I _{EBO}	1	1	-1	μ A	V _{EB} = -4V	
Collector-emitter staturation voltage	$V_{\text{CE(sat)}}$	1	-200	-400	mV	I_C = -300mA, I_B = -15mA	
DC current gain	h _{FE}	120	1	390	-	V_{CE} = -3V, I_{C} = -100mA	
Transition frequency	f _T	ı	380	ı	MHz	V _{CE} = -10V I _E =200mA, f=100MHz	
Collector output capacitance	C _{ob}	-	10	-	pF	V _{CB} = -10V, I _E =0A f=1MHz	
Turn-on time	t _{on} *	-	50	-	ns	I _C = -0.35A, I _{B1} = -35mA, I _{B2} =35mA, V _{CC} <u>~</u> -10V	
Storage time	t _{stg} *	-	350	-	ns		
Fall time	t _f *	-	50	-	ns		

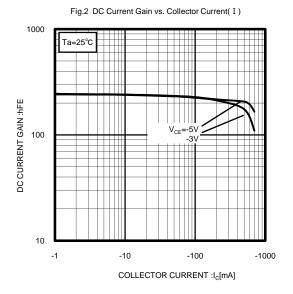
^{*} See switching time test circuit

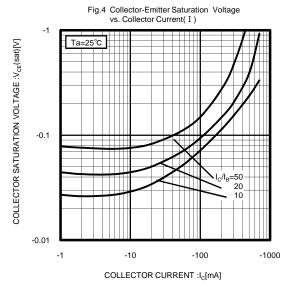
●Electrical characteristic curves (Ta = 25°C)











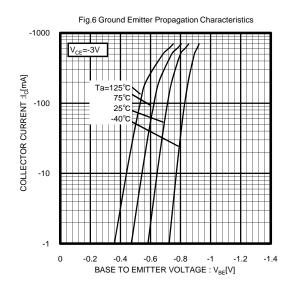
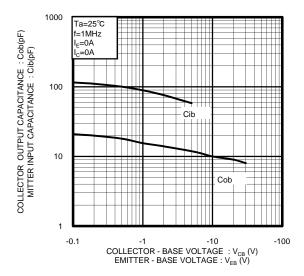


Fig.7 Emitter input capacitance vs. Emitter-Base Voltage Collector output capacitance vs.Collector-Base Voltage



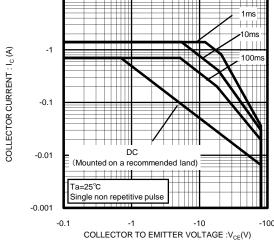
Ta=25°C V_{CE}=-10V Ta=25°C V_{CE}=-10°C V_{CE}=-1

 $\mathsf{EMITTER}\;\mathsf{CURRENT}: \mathsf{I}_\mathsf{E}[\mathsf{A}]$

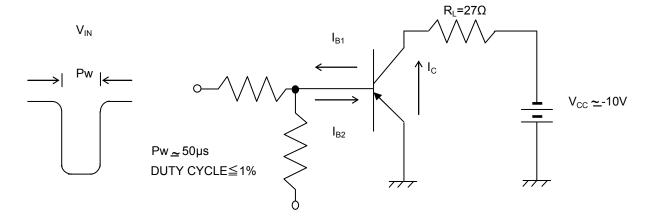
Fig8. Gain Bandwidth Product vs. Emitter Current

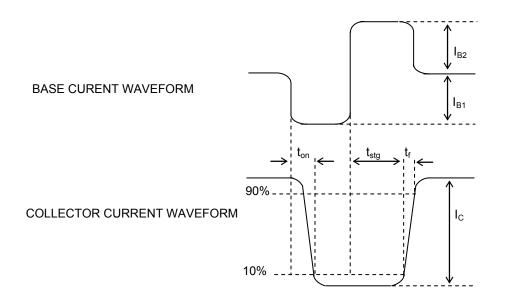
1000





• Switching time test circuit





Notes

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